

Semiconductor 1.7 W Volume Bragg Laser with Divergence Close to a Diffraction Limit

George Venus, Vasile Rotar, and Leonid Glebov

CREOL, University of Central Florida, P.O. Box 162700, Orlando, FL 32816-2700
Tel. (407) 823-6800, Fax (407) 823-6880, E-mail: gvenus@creol.ucf.edu

Abstract: Novel volume Bragg laser (VOBLA) with two photo-thermo-refractive volume Bragg gratings feedback is studied on the basis of 150- μm -stripe LD. High-efficient, near diffraction-limited operation at power of 1.7W and spectral width of 250pm are demonstrated.

©2004 Optical Society of America

OCIS codes: (140.5960) Semiconductor lasers, (090.7330) Volume holographic gratings

The use of external resonators for improvement of spatial parameters of high power semiconductor lasers has been under intensive investigation for last 20 years. However, all desirable features such as diffraction limited divergence combined with high spectral brightness at high levels of pumping are not achieved yet [1-5]. The proposed solution of the problem is the use of an external cavity with two volume Bragg gratings for selection of a single transverse mode. Key elements for a considered construction are high-efficient volume Bragg gratings recorded in photo-thermo-refractive (PTR) glass [6, 7]. High-efficient transmitting volume Bragg gratings provide complete selection directly in space of wave vectors with very high angular selectivity while reflective Bragg gratings serve as feedback mirror with high spectral and angular selectivity. The used PTR Bragg gratings had absolute diffraction efficiency about 98% and were stable in high power laser beams and at elevated temperatures.

Optical design of volume Bragg laser used in this work is shown in Fig. 1. A 150- μm -stripe laser diode (LD) with antireflection (AR) coating at the front facet providing reflection $\sim 0.5\%$ was pumped by pulse current. Its radiation was collimated along the fast axis and was not collimated along the slow axis. As for wide-stripe LD dominant modes manifest off-axis emission with two main lobes, a transmitting Bragg grating was aligned in such way that diffracted maximum power from one of these lobes. The used transmitting Bragg grating with 98% diffraction efficiency had angular selectivity of 0.65 deg (FWHM). Such angular selectivity corresponds to near diffraction limited beam divergence for laser with 150- μm -stripe. A reflecting Bragg-grating with 98% diffraction efficiency reflected diffracted beam back to resonator and thereby provided necessary feedback. In other words we could select a single high-order mode of internal LD cavity within a wide range of pumping current. The first main lobe of this high-order mode was used for feedback. The second lobe did not interact with both Bragg gratings due to their narrow angular selectivity and was used as an output beam with near diffraction limited divergence. The total length of a proposed LD with an external cavity did not exceed 4-5 mm and was limited only by the used mechanical parts.

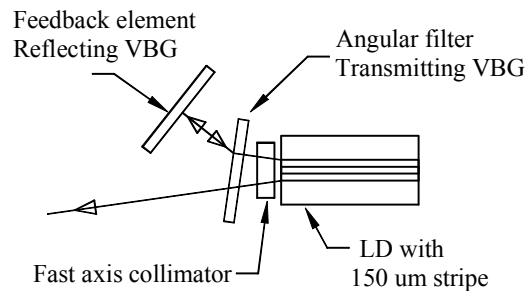


Fig.1 Semiconductor volume Bragg laser with a transmitting grating as an angular selective element and a reflecting grating as a feedback mirror with spectral and angular selectivity.

Feedback provided by the Bragg gratings resulted in narrowing of the angular divergence to the near diffraction limit with FWHM=0.6° (Fig. 2). Increasing of pumping up to 8 thresholds results in increasing of the background radiation but the single mode regime is controlled by PTR volume Bragg grating within the whole region of pumping. This increasing of spatial brightness is accompanied by significant narrowing of the spectral width down to 250 pm (Fig. 3).

Report Documentation Page				Form Approved OMB No. 0704-0188	
Public reporting burden for the collection of information is estimated to average 1 hour per response, including the time for reviewing instructions, searching existing data sources, gathering and maintaining the data needed, and completing and reviewing the collection of information. Send comments regarding this burden estimate or any other aspect of this collection of information, including suggestions for reducing this burden, to Washington Headquarters Services, Directorate for Information Operations and Reports, 1215 Jefferson Davis Highway, Suite 1204, Arlington VA 22202-4302. Respondents should be aware that notwithstanding any other provision of law, no person shall be subject to a penalty for failing to comply with a collection of information if it does not display a currently valid OMB control number.					
1. REPORT DATE 2004		2. REPORT TYPE		3. DATES COVERED 00-00-2004 to 00-00-2004	
4. TITLE AND SUBTITLE Semiconductor 1.7 W Volume Bragg Laser with Divergence Close to a Diffraction Limit				5a. CONTRACT NUMBER	
				5b. GRANT NUMBER	
				5c. PROGRAM ELEMENT NUMBER	
6. AUTHOR(S)				5d. PROJECT NUMBER	
				5e. TASK NUMBER	
				5f. WORK UNIT NUMBER	
7. PERFORMING ORGANIZATION NAME(S) AND ADDRESS(ES) University of Central Florida, College of Optics & Photonics/CREOL, PO Box 162700, Orlando, FL, 32816-2700				8. PERFORMING ORGANIZATION REPORT NUMBER	
9. SPONSORING/MONITORING AGENCY NAME(S) AND ADDRESS(ES)				10. SPONSOR/MONITOR'S ACRONYM(S)	
				11. SPONSOR/MONITOR'S REPORT NUMBER(S)	
12. DISTRIBUTION/AVAILABILITY STATEMENT Approved for public release; distribution unlimited					
13. SUPPLEMENTARY NOTES					
14. ABSTRACT					
15. SUBJECT TERMS					
16. SECURITY CLASSIFICATION OF:			17. LIMITATION OF ABSTRACT	18. NUMBER OF PAGES 2	19a. NAME OF RESPONSIBLE PERSON
a. REPORT unclassified	b. ABSTRACT unclassified	c. THIS PAGE unclassified			

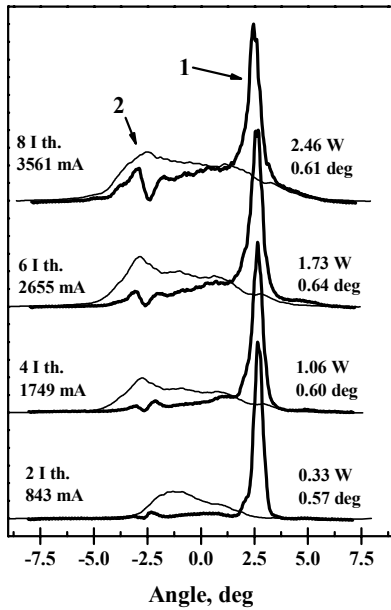


Fig. 2. Far field pattern for VOBLA (1) with the reflective grating and for free running LD (2).

Output power versus pumping current is shown in Fig. 4 for VOBLA and free running LD in the same arrangement with detuned Bragg grating (Fig. 1). The grating feedback reduced threshold current by 1.45 times to 370 mA. Slope efficiency for VOBLA (0.784 W/A) was 98% of that for the free running LD. Absolute reduction of slope efficiency for about 14% compare to that in an original LD (0.91 W/A) is caused by Fresnel reflection of the used transmitting PTR gratings that had no AR coating.

Thus, semiconductor VOBLA having simple and robust design, provides high power emission with near diffracted limited divergence, high-spectral brightness with efficiency close to that of the free running LD.

The work was supported by DARPA SHEDS program contract HR-01-1041-0004. Authors thanks Larissa Glebova, Ina Ciapurina, and Julien Lumeau for PTR glass preparing and certification.

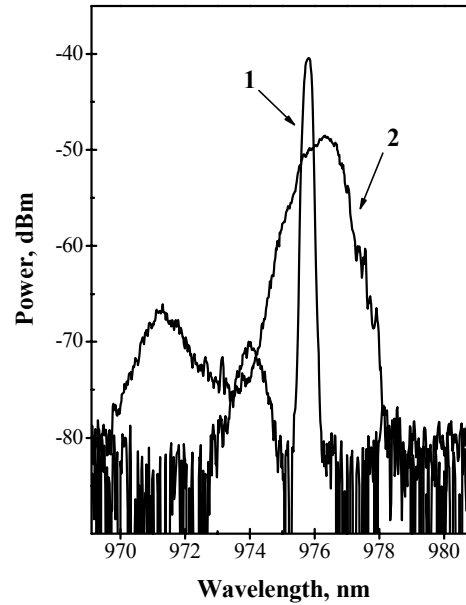


Fig. 3. Spectra of the semiconductor volume Bragg laser (1) and free running LD (2) at $8I_{th}$ pumping current (3561 mA).

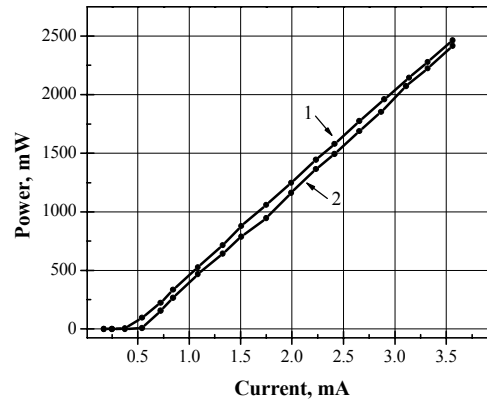


Fig. 4. Light-current charecteristic for the semiconductor volume Bragg laser (1) and the free running laser diode (2).

1. C.J. Chang-Hasnain, J. Berger, D.R. Scifres, W. Streifer, J.R. Whinnery and A. Dienes "High power with high efficiency in a narrowing single-lobed beam from a diode laser array in an external cavity" *Appl. Phys. Lett.* **50**(21) 1987
2. A.Barthelemy, F. Louradour and V. Coudere "Wavelength-tunable diffraction limited operation of a standard high-power diode array using an of-centered extended cavity" *Elect. Lett.* **28**(22), 2038, 1992
3. M. Lobel, P.M. Petersen, and P.M. Johansen "Single-mode operation of a laser-diode array with frequency-selective phase-conjugate feedback" *Opt. Lett.* **23**(11), 825 (1998)
4. V. Raab and R. Menzel "External resonator design for high-power laser diodes that yields 400 mW of TEM00 power". *Opt. Lett.* **27**(3), 167 (2002)
5. S. Yiou, F. Balembois, P. Georges and J. Huignard "Improvement of the spatial beam quality of laser sources with an intracavity Bragg grating" *Opt. Lett.* **28**(4), 242 (2003)
6. O.M. Efimov, L.B. Glebov, V.I. Smirnov, and L.N. Glebova, "Process for production of high efficiency volume diffractive elements in photo-thermo-refractive glass," U.S. Patent **6,586,141** (2003).
7. O.M. Efimov, L.B. Glebov, and V.I. Smirnov, "High efficiency volume diffractive elements in photo-thermo-refractive glass," U.S. Patent **6,673,497** (2004).